74HC151; 74HCT151

8-input multiplexer
Rev. 5 — 26 January 2015

Product data sheet

1. **General description**

The 74HC151; 74HCT151 are 8-bit multiplexer with eight binary inputs (I0 to I7), three select inputs (S0 to S2) and an enable input (E). One of the eight binary inputs is selected by the select inputs and routed to the complementary outputs (Y and \overline{Y}). A HIGH on \overline{E} forces the output Y LOW and output Y HIGH. Inputs also include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2.

- Specified in compliance with JEDEC standard no. 7A
- Input levels:
 - ◆ For 74HC151: CMOS level
 - ◆ For 74HCT151: TTL level
- Low-power dissipation
- Non-inverting data path
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2 000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

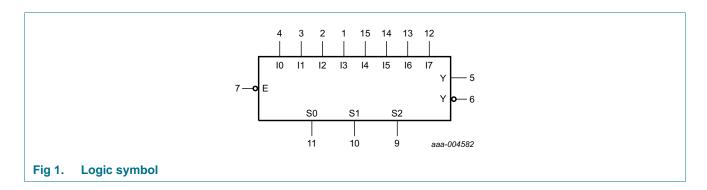
Ordering information 3.

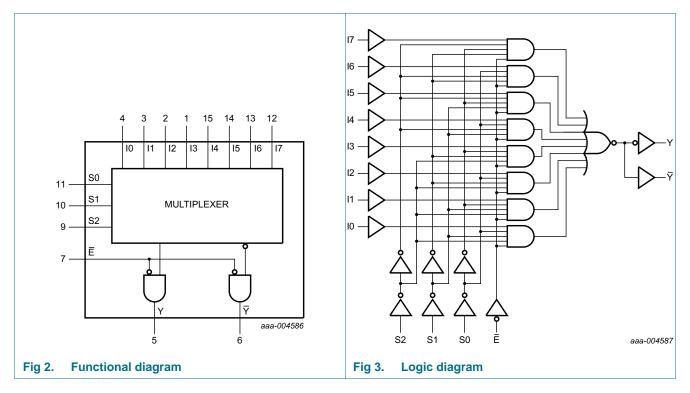
Ordering information Table 1.

Type number	Package	Package									
	Temperature range	Name	Description	Version							
74HC151N	-40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4							
74HCT151N											
74HC151D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width	SOT109-1							
74HCT151D			3.9 mm								
74HC151DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1							
74HCT151DB			body width 5.3 mm								
74HC151PW	-40 °C to +125 °C	TSSOP16	process and comments processed by the comments								
74HCT151PW			body width 4.4 mm								



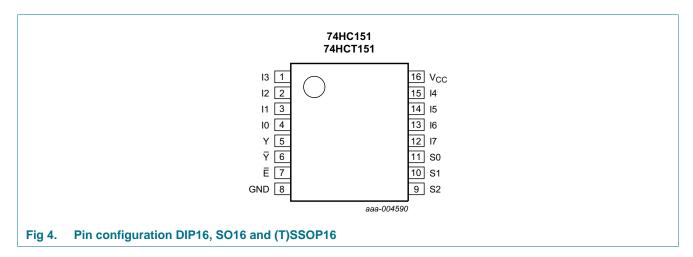
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
10 to 17	4, 3, 2, 1, 15, 14, 13, 12	data inputs
Υ	5	multiplexer output
Y	6	complementary multiplexer output
Ē	7	enable input (active LOW)
GND	8	ground (0 V)
S0, S1, S2	11, 10, 9	common data select inputs
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table[1]

Input												Outp	ut
E	S2	S1	S0	10	l1	12	13	14	15	16	17	Y	Υ
Н	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Н	L
L	L	L	L	L	Х	Х	Х	Х	Х	Х	Х	Н	L
L	L	L	L	Н	Х	Х	Х	Х	Х	Х	Х	L	Н
L	L	L	Н	Х	L	Х	Х	Х	Х	Х	Х	Н	L
L	L	L	Н	Х	Н	Х	Х	Х	Х	Х	Х	L	Н
L	L	Н	L	Х	X	L	Х	Х	Х	Х	Х	Н	L
L	L	Н	L	Х	X	Н	Х	Х	Х	Х	Х	L	Н
L	L	Н	Н	Х	Х	Х	L	Х	Х	Х	Х	Н	L
L	L	Н	Н	Х	Х	Х	Н	Х	Х	Х	Х	L	Н
L	Н	L	L	Х	Х	Х	Х	L	Х	Х	Х	Н	L
L	Н	L	L	Х	Х	Х	Х	Н	Х	Х	Х	L	Н
L	Н	L	Н	Х	X	Х	Х	Х	L	Х	Х	Н	L
L	Н	L	Н	Х	Х	Х	Х	Х	Н	Х	Х	L	Н
L	Н	Н	L	Х	X	Х	Х	Х	Х	L	Х	Н	L
L	Н	Н	L	Х	Х	Х	Х	Х	Х	Н	Х	L	Н
L	Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	L	Н	L
L	Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	Н	L	Н

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C

 Table 4.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$			
	DIP16 package	[1]	-	750	mW
	SO16 package	[2]	-	500	mW
	(T)SSOP16 package	[3]	-	500	mW

- [1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.
- [2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.
- [3] For SSOP16 and TSSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC151		7	4HCT15	1	Unit	
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	ter Conditions		_{mb} = 25	°C		40 °C to 5 °C	T _{amb} = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC15	1									
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
	$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V	
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
C _I	input capacitance		-	3.5	-					pF

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Tai	_{mb} = 25	°C		40 °C to 5 °C		-40 °C to 25 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT1	51									
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 4.0 \text{ mA}$	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Δl _{CC}	additional supply current	$\begin{aligned} &V_{I} = V_{CC} - 2.1 \text{ V;} \\ &\text{other inputs at } V_{CC} \text{ or GND;} \\ &V_{CC} = 4.5 \text{ V to } 5.5 \text{ V;} \\ &I_{O} = 0 \text{ A} \end{aligned}$								
		per input pin; In inputs	-	45	162	-	203	-	221	μΑ
		per input pin; E input	-	30	108	-	135	-	147	μΑ
		per input pin; Sn input	-	150	540	-	675	-	735	μΑ
Cı	input capacitance		-	3.5	-					pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 7.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C		= –40 °C ⋅85 °C	T _{amb} =	-40 °C 125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC15	1						1			
t _{pd} propagation		In to Y; see Figure 5	<u>l]</u>							
	delay	V _{CC} = 2.0 V	-	52	170	-	215	-	255	ns
		V _{CC} = 4.5 V	-	19	34	-	43	-	51	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	15	29	-	37	-	43	ns
		In to \overline{Y} ; see Figure 5	1]							
		V _{CC} = 2.0 V	-	58	185	-	230	-	280	ns
		V _{CC} = 4.5 V	-	21	37	-	46	-	56	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	17	31	-	39	-	48	ns
		Sn to Y; see Figure 6	<u>l]</u>							
		V _{CC} = 2.0 V	-	61	185	-	230	-	280	ns
		V _{CC} = 4.5 V	-	22	37	-	46	-	56	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	19	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	18	31	-	39	-	48	ns
		Sn to \overline{Y} ; see Figure 6	<u>I]</u>							
		V _{CC} = 2.0 V	-	61	205	-	255	-	310	ns
		V _{CC} = 4.5 V	-	22	41	-	51	-	62	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	19	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	18	35	-	43	-	53	ns
		E to Y; see Figure 6								
		V _{CC} = 2.0 V	-	41	125	-	155	-	190	ns
		V _{CC} = 4.5 V	-	15	25	-	31	-	38	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	12	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	12	21	-	26	-	32	ns
		E to Y; see Figure 6								
		V _{CC} = 2.0 V	-	47	145	-	180	-	220	ns
		V _{CC} = 4.5 V	-	17	29	-	36	-	44	ns
		V _{CC} = 5 V; C _L = 15 pF	-	14	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	25	-	31	-	38	ns
t _t	transition		2]							
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 7.

Symbol	Parameter	Conditions		T _{an}	_{nb} = 25	°C		= –40 °C 85 °C	T _{amb} = -40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	
C_{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V_I = GND to V_{CC}	<u>[3]</u>	-	40	-	-	-	-	-	pF
74HCT1	51										
t _{pd}	propagation	In to Y; see Figure 5	<u>[1]</u>								
	delay	V _{CC} = 4.5 V		-	22	38	-	48	-	57	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
		In to \overline{Y} ; see Figure 5	<u>[1]</u>								
		V _{CC} = 4.5 V		-	22	38	-	48	-	57	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
		Sn to Y; see Figure 6	<u>[1]</u>								
		V _{CC} = 4.5 V		-	23	41	-	51	-	62	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		Sn to \overline{Y} ; see Figure 6	[1]								
		V _{CC} = 4.5 V		-	25	43	-	54	-	65	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		E to Y; see Figure 6	<u>[1]</u>								
		V _{CC} = 4.5 V		-	16	29	-	36	-	44	ns
		V _{CC} = 5 V; C _L = 15 pF		-	13	-	-	-	-	-	ns
		E to Y; see Figure 6	[1]								
		V _{CC} = 4.5 V		-	21	36	-	45	-	54	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	18	-	-	-	-	-	ns
t _t	transition	Y, \overline{Y} ; see Figure 5	[2]								
	time	V _{CC} = 4.5 V		-	7	15	-	19	-	22	ns
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V_I = GND to V_{CC} – 1.5 V	[3]	-	40	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] $\ t_t$ is the same as t_{THL} and $t_{TLH}.$
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

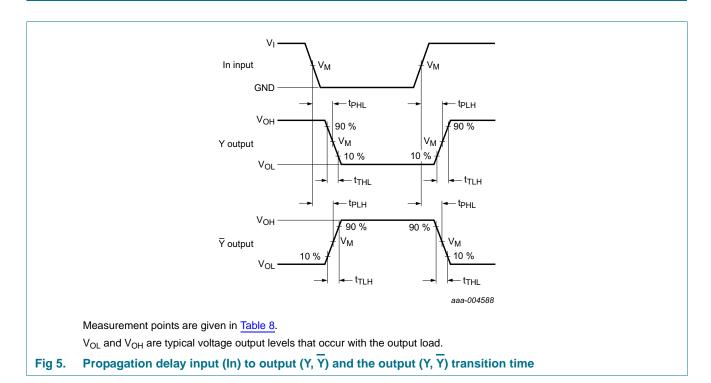
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

11. Waveforms



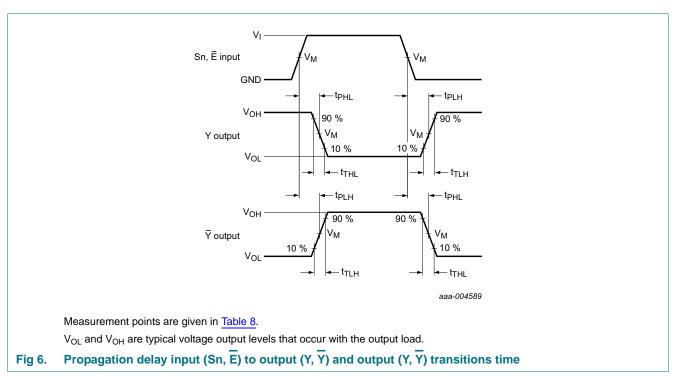
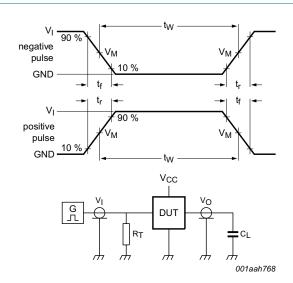


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC151	0.5V _{CC}	0.5V _{CC}
74HCT151	1.3 V	1.3 V



Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

S1 = Test selection switch.

Fig 7. Test circuit for measuring switching times

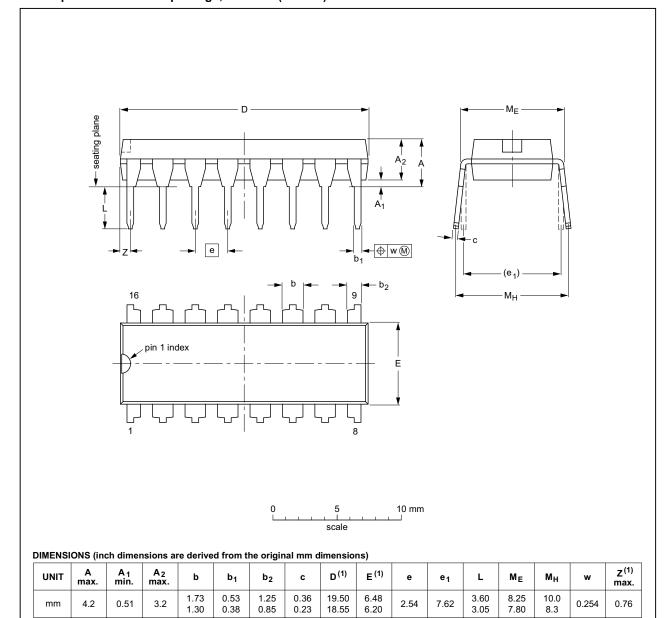
Table 9. Test data

Туре	Input Le		Load	Test
	V _I	t _r , t _f	C _L	
74HC151	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT151	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



inches

0.17

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.021

0.049

0.033

0.014

0.068

0.13

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT38-4					95-01-14 03-02-13

0.77

0.26

0.1

Fig 8. Package outline SOT38-4 (DIP16)

0.02

74HC_HCT151

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0.01

0.03

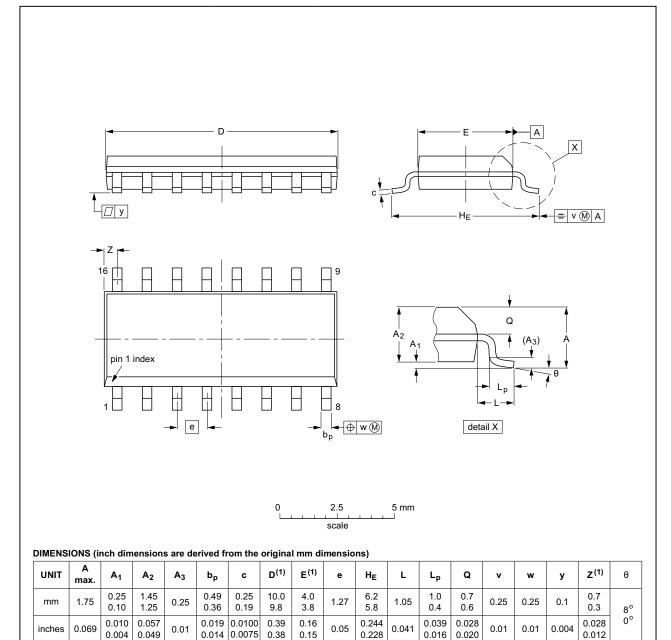
0.32

0.14

0.39

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

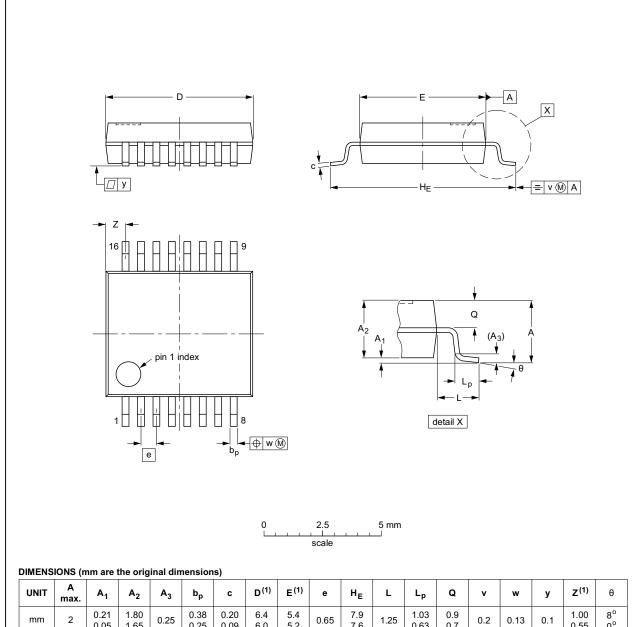
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			99-12-27 03-02-19

Fig 9. Package outline SOT109-1 (SO16)

74HC_HCT151

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT338-1		MO-150				99-12-27 03-02-19

Fig 10. Package outline SOT338-1 (SSOP16)

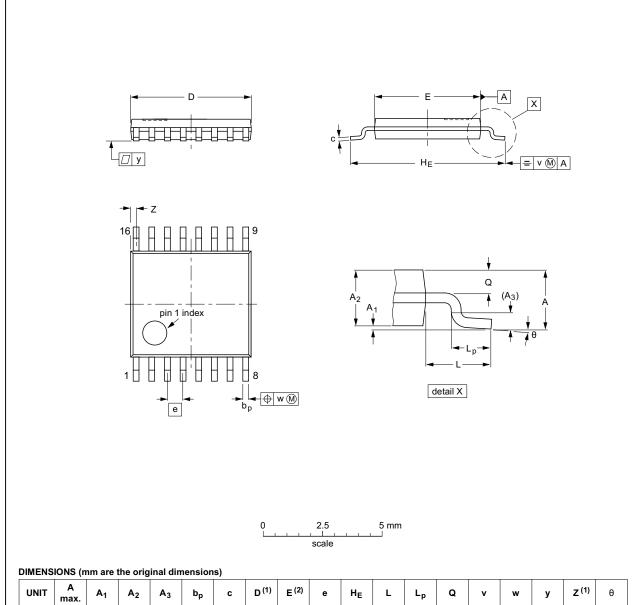
74HC_HCT151

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNI	IT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E (2)	e	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mn	n	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTL	LINE		REFER	RENCES	EUROPEAN	ICCLIE DATE	
VERS	SION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE -99-12-27	
SOT4	403-1		MO-153			-99-12-27 03-02-18	
SOT4	403-1		MO-153)	

Fig 11. Package outline SOT403-1 (TSSOP16)

74HC_HCT151

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT151 v.5	20150126	Product data sheet	-	74HC_HCT151 v.4
Modifications:	• <u>Table 7</u> : Pov	wer dissipation capacitance	e condition for 74HCT	151 is corrected.
74HC_HCT151 v.4	20130211	Product data sheet	-	74HC_HCT151 v.3
Modifications:	New descrip	otive title (errata).		
74HC_HCT151 v.3	20120919	Product data sheet	-	74HC_HCT151_CNV v.2
74HC_HCT151_CNV v.2	19970827	Product specification	-	

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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74HC151; 74HCT151

NXP Semiconductors

8-input multiplexer

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